



Calculated Cluster Sizes for RPCs



Christian Lippmann, CERN

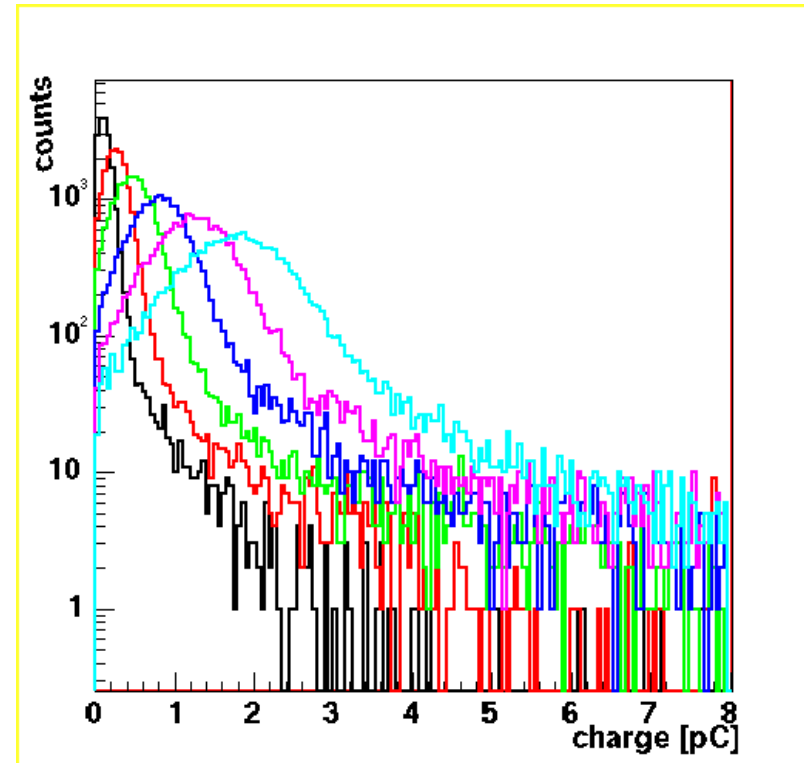
- ◆ **Cluster Sizes (=CIS) in RPC (1gap/2gap)**



Monte Carlo I



- ◆ Three pads (58mm width)
- ◆ The charge that is induced on the center pad is taken from real charge spectra (thanks to Gerardo)
- ◆ HV = 9.25kV, 9.5kV, 9.75kV, 10.0kV, 10.25kV, 10.5kV
- ◆ Tails up to 8pC

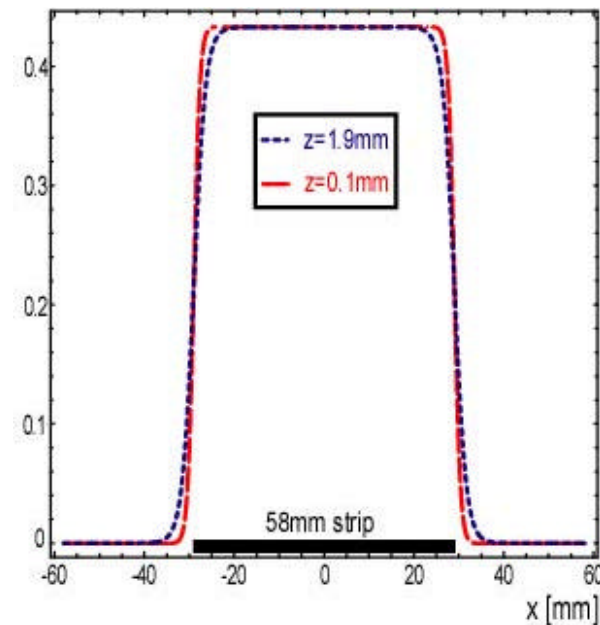
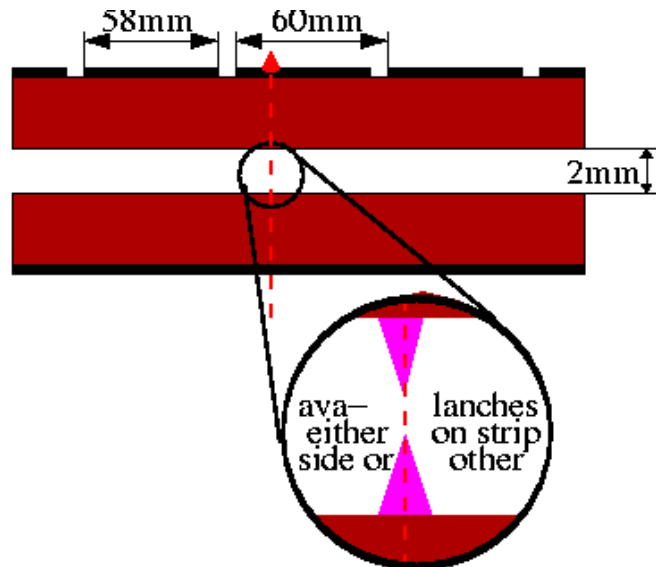




Monte Carlo II



- ◆ Random perpendicular tracks (Testbeam)
- ◆ Use Weighting Field (WF) to calculate direct X-talk on neighbor pads
 - Avalanches either on strip side or other side \Rightarrow different induced charges
- ◆ Add capacitive X-talk: 0% ... 10% (pulse height ratio)
- ◆ $Q_{ind}(x) = Q_{ind}(x=0) \cdot WF(x) / WF(x=0)$
- ◆ WF in RPCs: CERN-OPEN-2001-004 or CERN-EP-2001-074

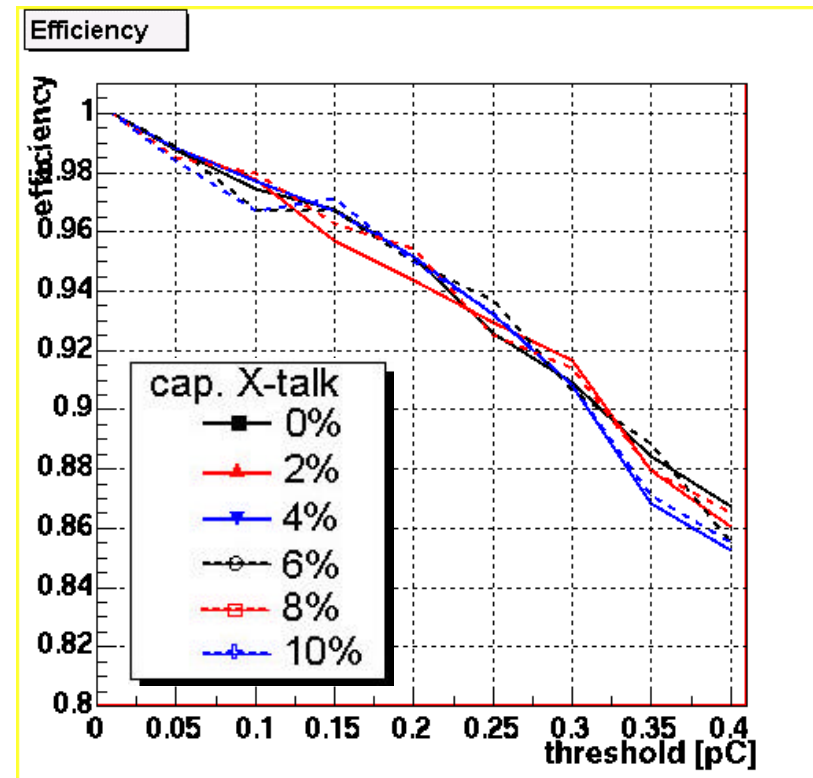




1 Gap; 10kV; Efficiency



- ◆ There is no difference if avalanche is on strip side or other side
- ◆ Capacitive X-talk does not influence the efficiency
- ◆ Thr = 100fC \Rightarrow Eff = 97-98%

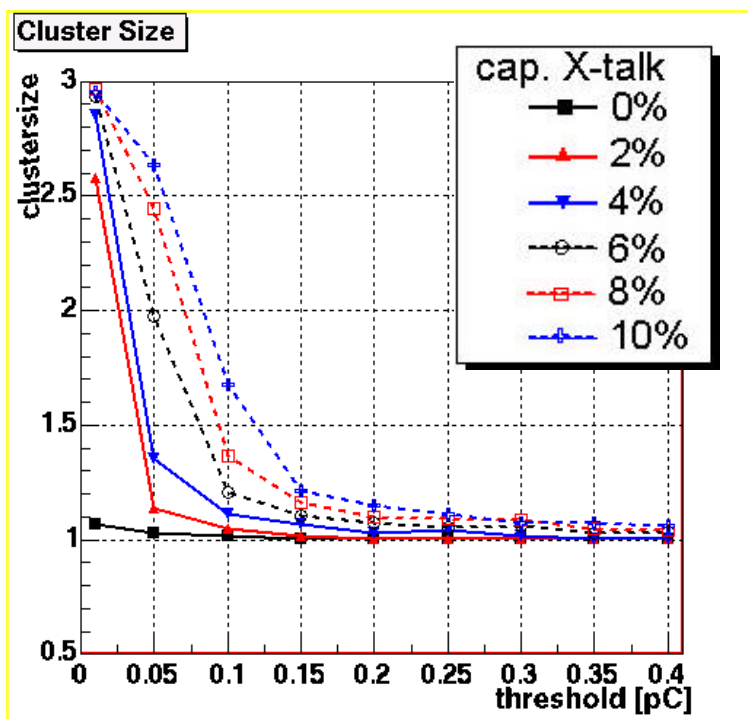




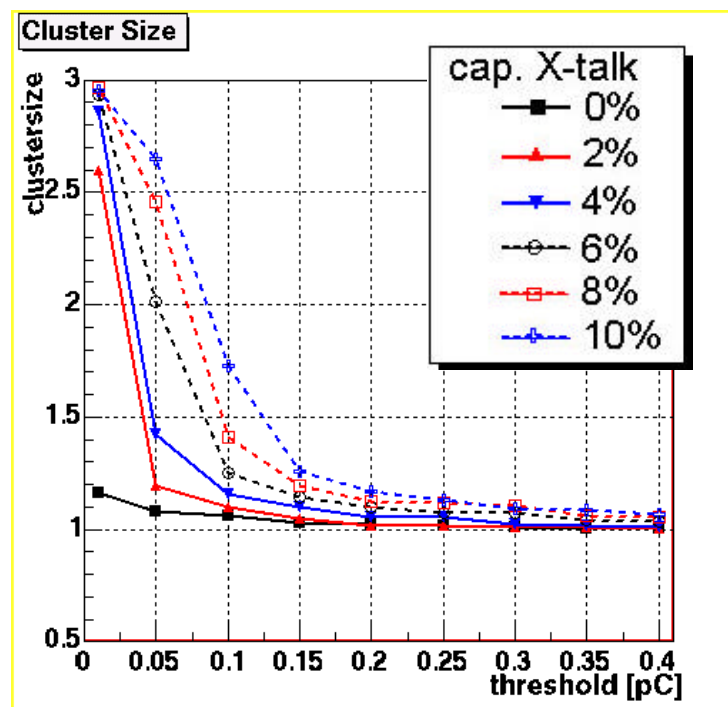
1 Gap; 10kV; Cluster Size



◆ Avalanches at side of strips



◆ Avalanches at opposite side of strips



◆ Very small difference

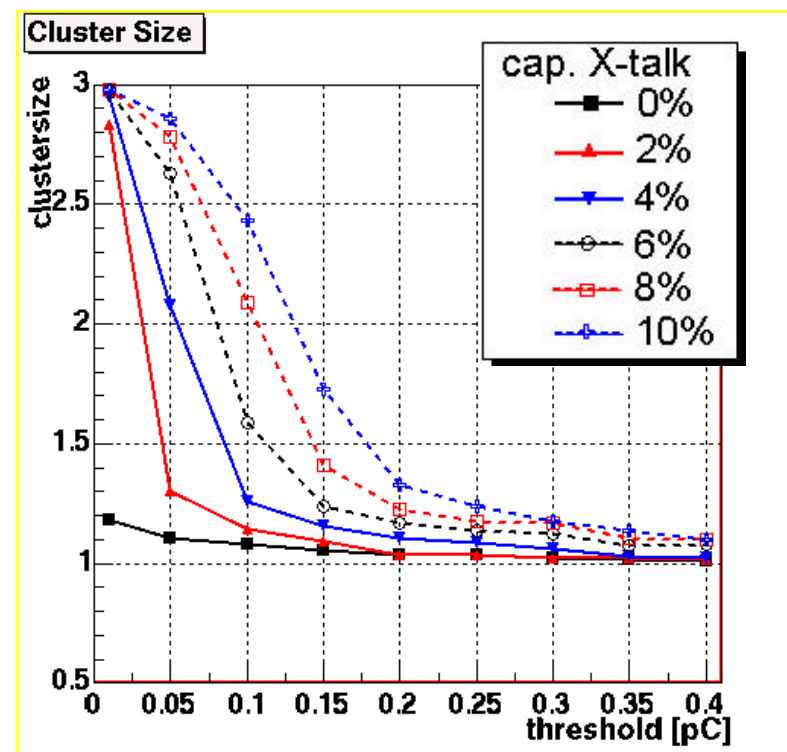
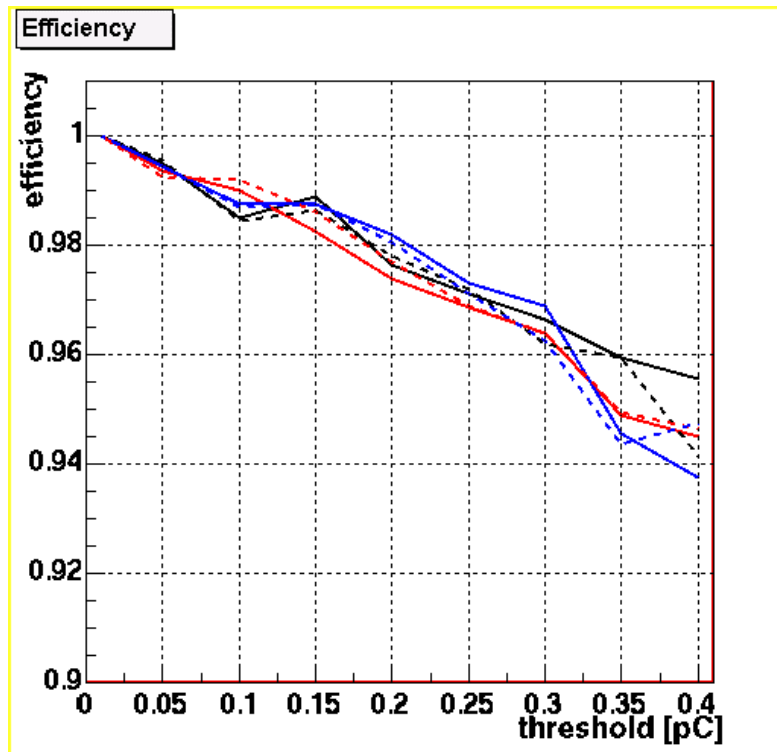
◆ Thr = 100fC \Rightarrow Eff = 97-98%; CIS = 1.1 ... 1.75



1 Gap; 10.25kV



◆ Thr = 100fC \Rightarrow Eff = 99%; CIS = 1.1 ... 2.4

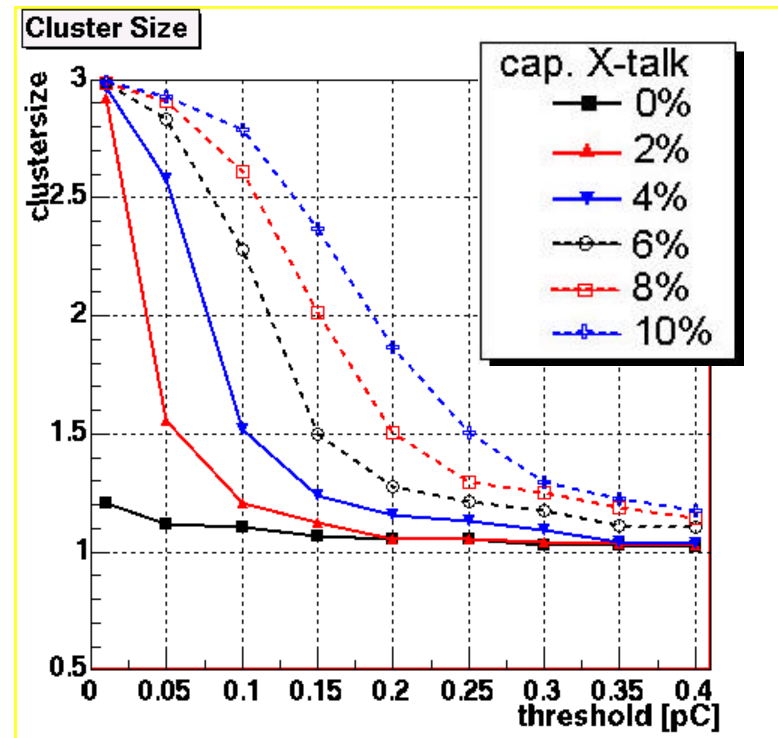
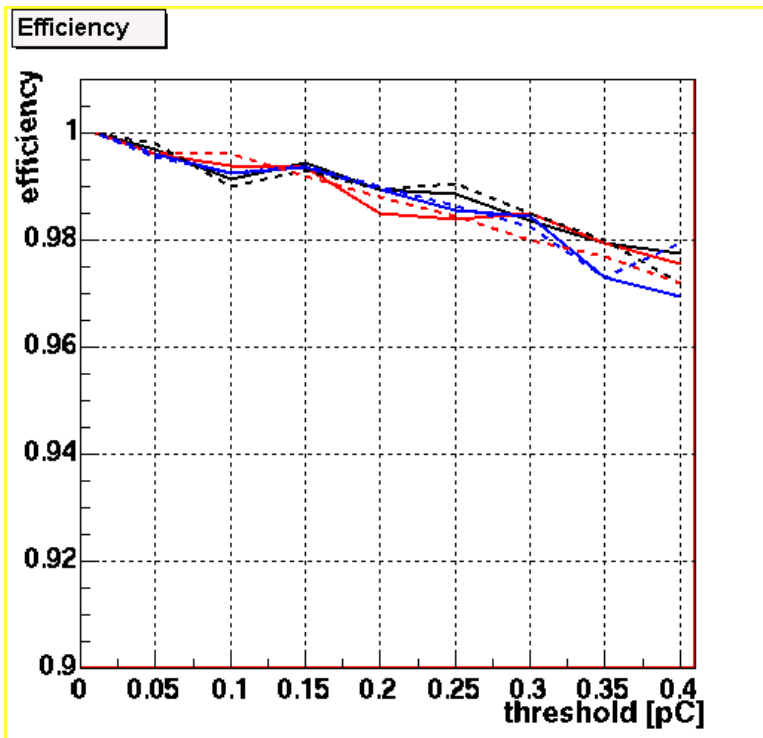




1 Gap; 10.5kV

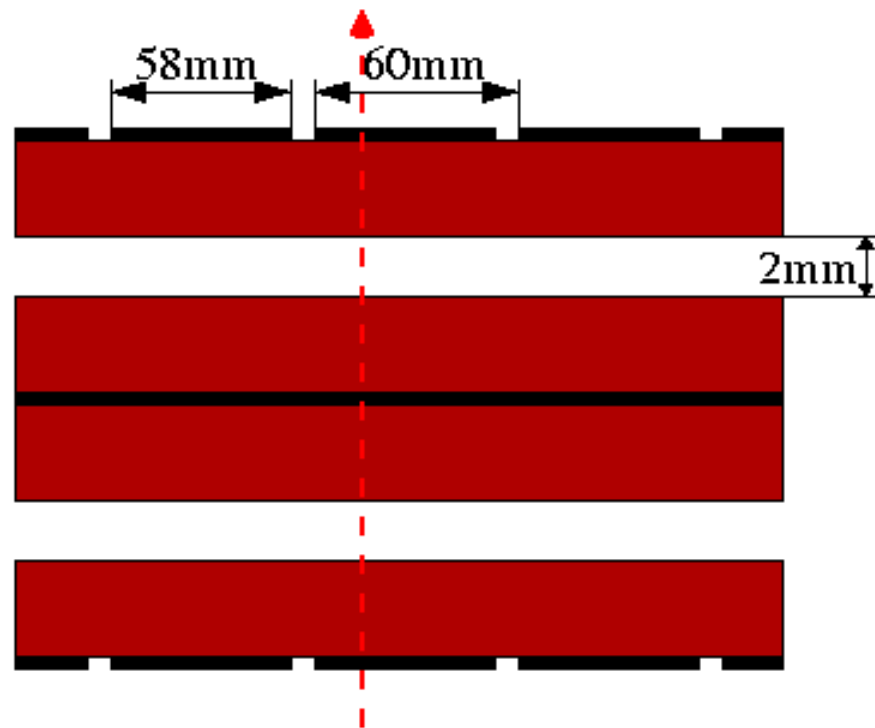


◆ Thr = 100fC \Rightarrow Eff = 99.5%; CIS = 1.1 ... 2.8





2 Gaps

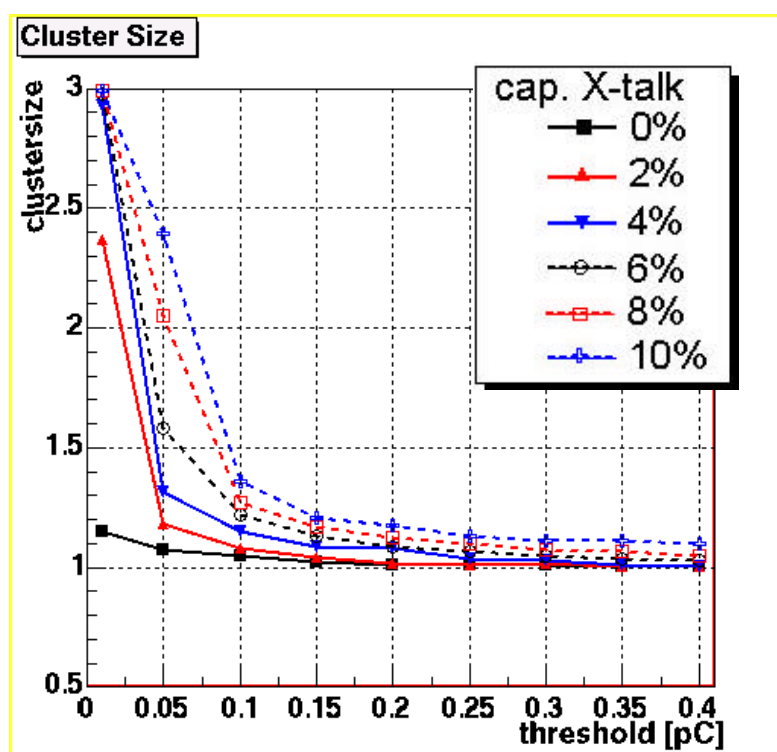
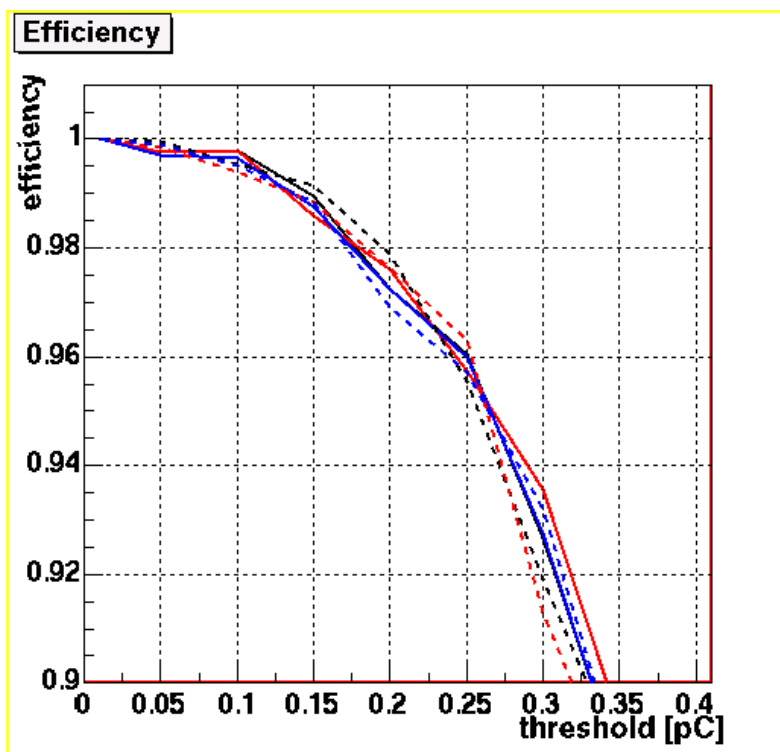




2 Gaps; 9.75kV



◆ Thr = 100fC \Rightarrow Eff = 99.5%; CIS = 1.05 ... 1.35

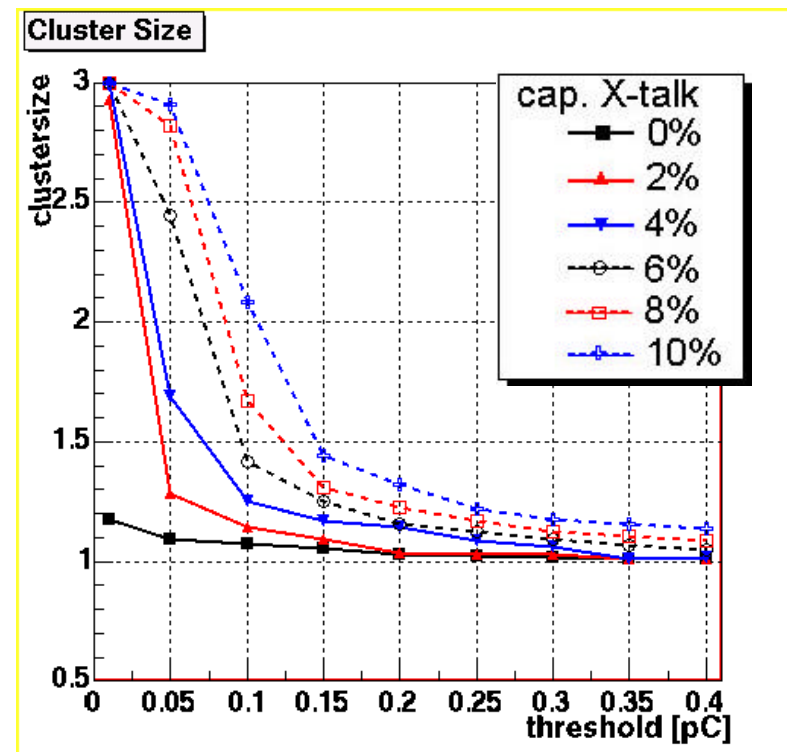
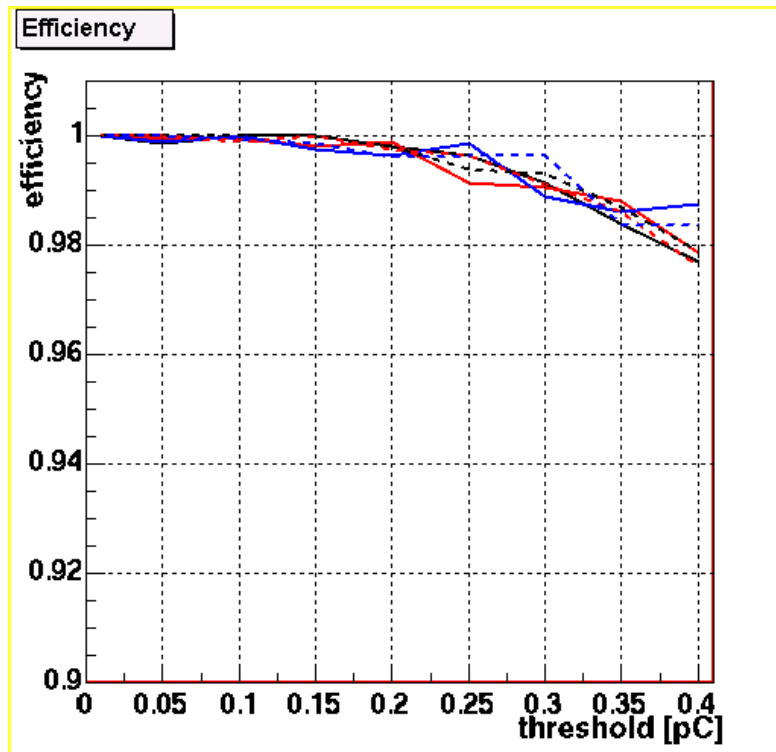




2 Gaps; 10kV



- ◆ Thr = 100fC \Rightarrow Eff = 100%; CIS = 1.1 ... 2.1

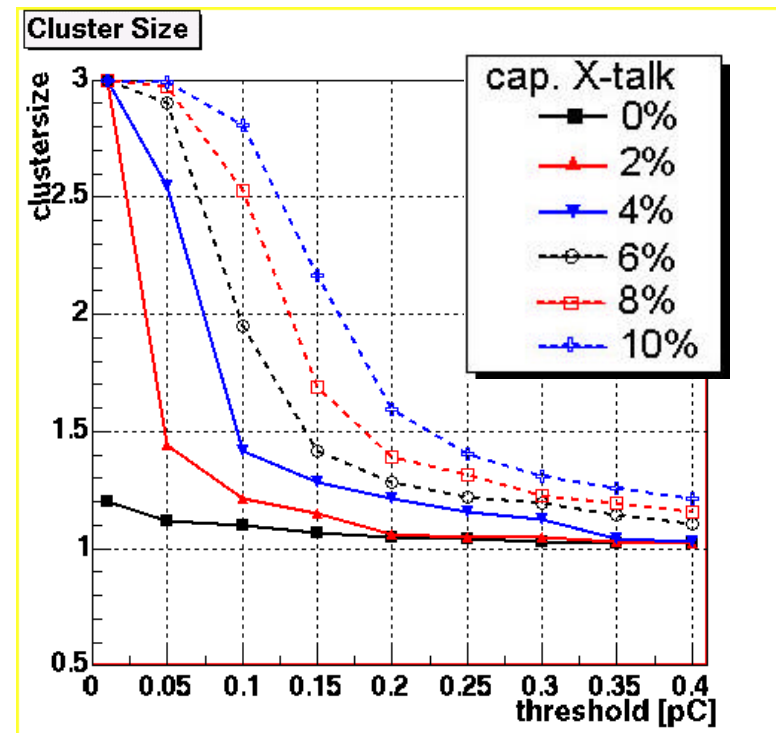
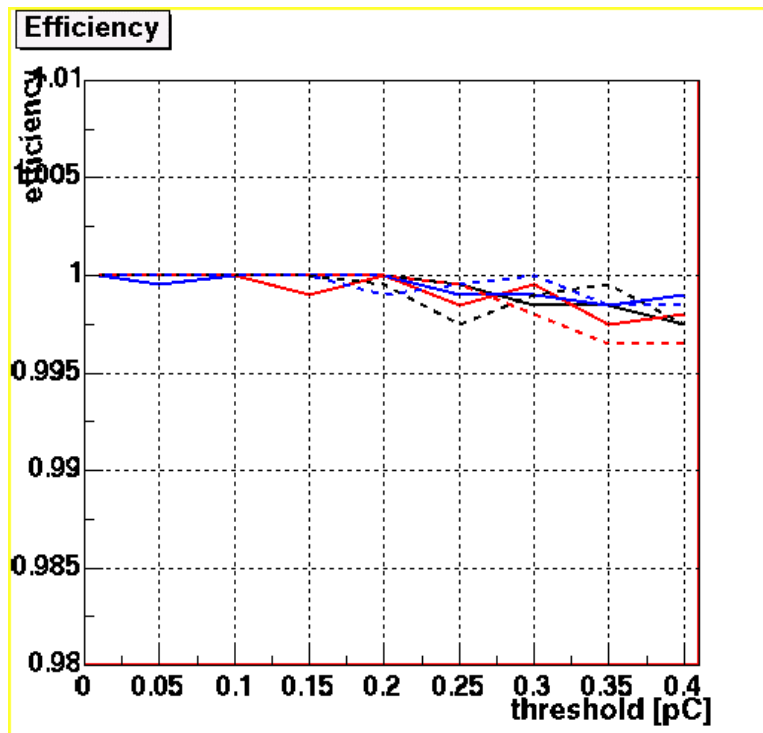




2 Gaps; 10.25kV



- ◆ Thr = 100fC \Rightarrow Eff = 100%; CIS = 1.1 ... 2.8

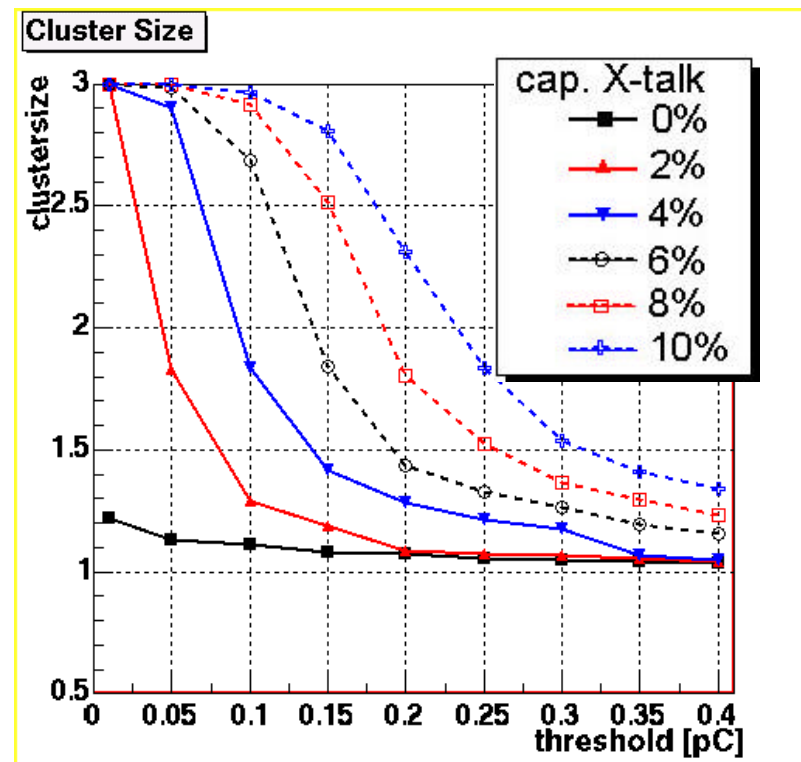
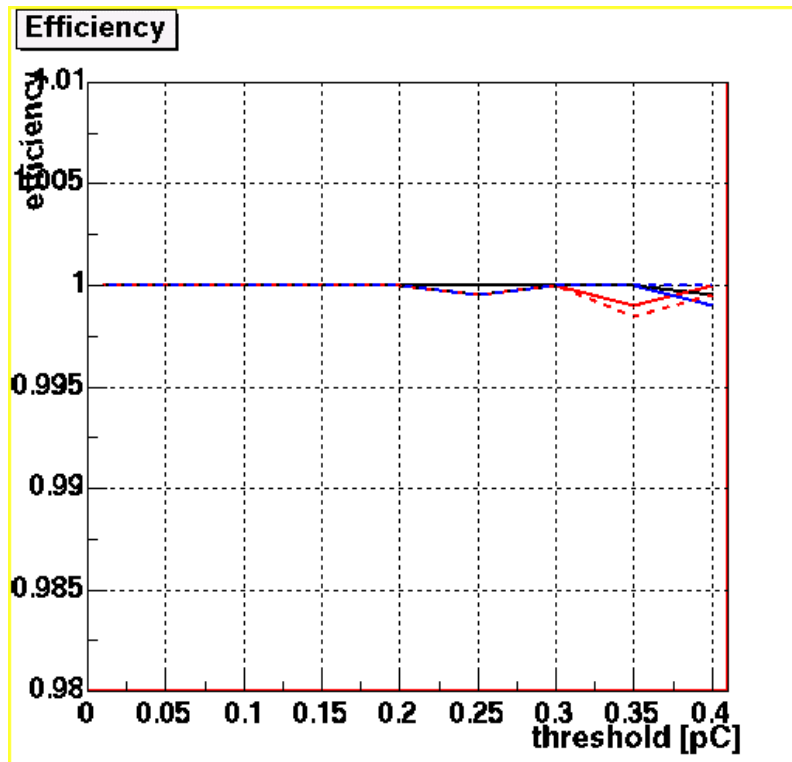




2 Gaps; 10.5kV



- ◆ Thr = 100fC \Rightarrow Eff = 100%; CIS = 1.15 ... 3.0





Summary/Conclusions



- ◆ **CIS and Efficiency are similar for the two orientations of the avalanche**
- ◆ **CIS is influenced largely by capacitive X-talk**
- ◆ **1 Gap; Threshold 100fC; 2% (4%) capacitive X-talk: 99.5% Efficiency at 10.5kV with CIS 1.2 (1.5)**
- ◆ **2 Gaps; Threshold 100fC; 2% (4%) capacitive X-talk: 99.5% Efficiency at 9.75kV with CIS 1.1 (1.2)**